

## 长春新产业光电技术有限公司

Changchun New Industries Optoelectronics Tech, Co., Ltd,

DATA SHEET

MLL-III-660D /1~1000mW

## SPECIFICATIONS

## LOW NOISE RED DIODE LASER At 660nm

Low noise red diode laser 660nm is made features of ultra compact, long lifetime, low cost and easy operating, which is widely used in measurement, spectrum analysis, laser lighting show, etc.



Wavelength (nm)	660 ± 5		
Output power (mW)	>1, 100, 200, , 1000		
Transverse mode	Near TE <sub>00</sub>		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Noise of amplitude (rms, 1~20MHz)	<1%		
Warm-up time (minutes)	<10		
M <sup>2</sup> factor	<20		
Beam divergence, full angle (mrad)	<2.5		
Dimensions of beam at the aperture (mm)	~5×8		
Beam height from base plate (mm)	24.8		
Polarization ratio	>50:1		
Pointing stability after warm-up (mrad)	<0.05		
Operating temperature (°C)	10~35		
Power supply (90-264VAC or 5VDC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
Expected lifetime (hours)	10000		
Warranty	1 year		





MLL-III-660D	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
		DPSSL DRIVER	
136(L)×73(W) ×46. 2(H) mm <sup>3</sup> , 0.6kg	153 (L) ×155(W) ×92 (H) mm <sup>3</sup> , 1.5kg	133 (L) ×130(W) ×65 (H) mm <sup>3</sup> , 1.2kg	100 (L) ×62(W) ×56 (H) mm <sup>3</sup> , 0.2kg